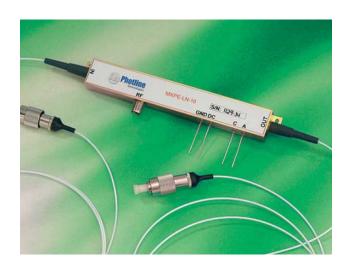
High Extinction Ratio LiNbO₃ Intensity Modulators KGMXPE-LN series



Description

The KGMXPE-LN series intensity modulators are a family of high performance modulators that exhibit superior extinction ratio. Their specific design relies on Proton Exchange, a diffusion process that creates polarizing waveguides in the lithium niobate substrate and leads to Extinction Ratio higher than 40 dB.

The KGMXPE-LN series intensity modulators have proven themselves as key devices in a variety of applications: pulse shaping prior optical amplification, pulse generation and lidar based sensing systems are a few examples.

Features

- Superior Extinction Ratio: 40 dB
- High Optical Power Handling: 500 mW
- Proton Exchanged processed, polarizing waveguides
- High Bandwidth (up to > 10 GHz)
- Broad wavelength range, work in C band and L band
- Bias electrode separated from RF input for easy implementation : no need for bias T

Options

- Internal monitoring photodiode
- Choice of input and output fibers
- 1300 nm and 1000 nm band versions
- Higher and lower modulation bandwidths

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网址: www.conquer-oc.com



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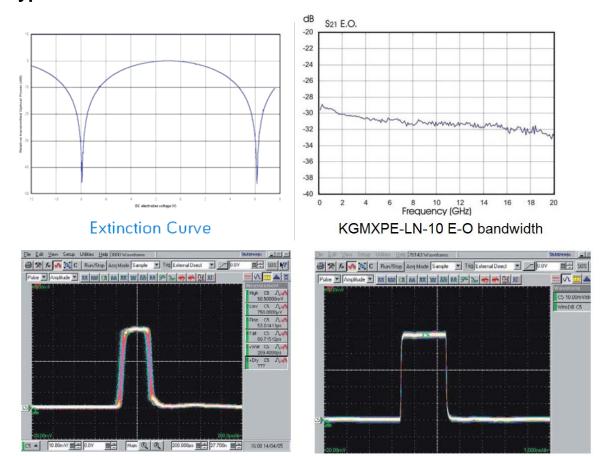
Specifications

Electrical			Min	Тур	Max
Vπ DC electrodes		V		7.0	7.5
KGMXPE-LN-10 electro- optic bandwidth S21 @-3 dB		GHz	10	12	
KGMXPE-LN-10 V_ RF electrodes @ 50 kHz		V		6	6.5
KGMXPE-LN-10 V_ RF electrodes @ 10 GHz		V		6.5	7
KGMXPE-LN-10 typical rise time for 1 ns pulse		ps		50	
Electrical return loss S11 0-High cut-off E-O bandwidth		dB		- 12	-10
Ripple		dBre		0.5	1
Input resistance RF connector		Ω		40	
Input resistance DC connector		Ω		>1 M	
Internal photodiode responsivity (ref: input power)		A/W	0.015	0.025	0.035
Optical					
Crystal		Lithium Niobate X-Cut Y-Prop			
Waveguide process		Proton Exchange			
DC extinction ratio		dB	40	43	
Insertion loss		dB		4	5
Optical return loss		dB		-40	
Wavelength dependent loss (1480-1600 nm)		dB		0.5	1
Chirp parameter			-0.1	0	0.1
Extinction ratio of internal photodiode		dB		3	6
Interfaces					
length : 1.5		maintaining , Panda type			
		meter, buffer diameter : 900 μm			
length :		de type , SMF-28			
		th: 1.5 meter, buffer diameter: 900 μm			
		maintaining , Panda type			
		meter, buffer diameter : 900 μm			
Package size	100 x 15 x 9.5 mm3				
Input RF connector	Wiltron Female K				
DC connectors	pin feed through diameter 1.0 mm pin feed through diameter 1.0 mm				
			meter 1.0	mm	
Environmental 2004 7000					
Operating temperature	0°C to +70°C				
Storage temperature -40°C to +85					
Maximum Ratings					
Maximum DF input navar	±20V				
Maximum RF input power	+28dBm +27dBm				
Maximum optical input power					

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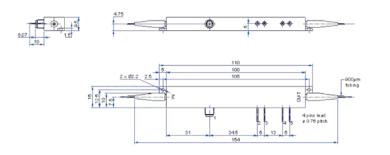
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Typical curves



256ps pulse generated with KGMXPE-LN-10 2ns pulse generated with KGMXPE-LN-10

Package footprint



2 GROUND

1 RF INPUT

3 BIAS INPUT

4 PHOTODIODE CATHODE

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5 PHOTODIODE ANODE

dimensions in mm

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